Dynamic Engineers Inc.

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 USA TEL: 1-281-870-8822 EMAIL:Sales@DynamicEng.com

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Features and Benefits

14DIP Compatible 8mm Height Packaging Very Low Power Consumption: 0.15W at +25°C

Fast Warming-up: 60 s typical

Low Aging: +/-3.0 ppb/day, +/-300 ppb/year

Typical Applications

Portable Wireless Communications Mobile Test equipment Synthesizers Battery Powered Application

Description

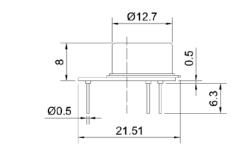
The OCXO3307LP-42.8MHz-A-V utilizes the internal heating resonator (IHR) technology incorporating the whole oven system together with the crystal plate inside the TO-8 vacuum holder. Such an OCXO concept results in radical reduction of its volume, power consumption and warm-up time. In spite of the miniature sizes and extremely low power consumption such oscillators exhibit excellent temperature stability, low phase-noise and aging rate being at the level of high-end OCXOs using conventional oven designs.

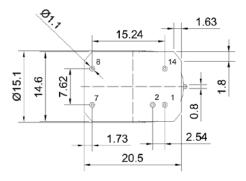
Mechanical Drawing & Pin Connections

Drawing No: N

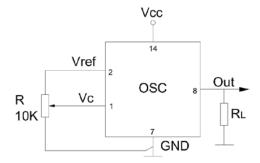
MD140075-1

Physical dimensions





Schematic connections



Pin	Signal
1	Electrical tuning
2	Reference voltage
7	GND
8	RF Out
14	+V Supply

Unit: mm



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Specifications

Oscillator Specification	Comm	Condition	Value			11.5			
	Sym		Min.	Тур.	Max.	Unit	Note		
Operational Frequency	F _{nom}			42.800000		MHz			
Initial tolerance		at +25°C, Vc=Vco	-0.2		+0.2	ppm			
RF Output		,							
Waveform : LVCMOS				HCMOS					
Load		5 pF in parallel with 10K		5//10K		pF//K			
I I level veltage		·							
H-level voltage		Vcc=3.3V	2.4			V			
L-level voltage					0.4	V			
Duty cycle			45		55	%			
Rise/Fall time					10	ns			
Sub-harmonics level				none					
Frequency control									
Control voltage range	V _c		0		2.8	V			
Frequency Turning Range			+/-0.5	+/-1	-	ppm	+		
Reference Voltage	V_{ref}			2.8		V			
Power Supply	1 1/		T		1		1		
Voltage	V _{cc}	W.		3.3		V			
Power consumption		Warm-up state		0.7		w			
		@ +25°C steady state		0.15					
		@ +25°C steady state		0.15			ref. to		
Warm-up Time:	T_{up}	to $\Delta f/f = 1e^{-7}$ at +25°C		60		S	frequencyafter 15		
Frequency Stability					,				
Vs.Temperature		Ref. 25°C			+/- 30	ppb			
Vs. Supply Voltage		Ref Vcc typ.		+/-2		ppb			
vs. direction		worst direction			+/-1	ppb/g			
Aging per day		after 30days of operation			+/-3	ppb			
first year					+/-300	ppb			
SSB Phase noise		1 Hz	ļ	-75	ļ				
		10 Hz		-105					
		100 Hz		-125		dBc/Hz			
		1 KHz		-145					
		10KHz		-155 -160	1				
Environmental Conditions		100 KHz		-160	<u> </u>				
Storage temperature range	-60°C to 00								
Operating temperature range		-60°C to 90°C -40°C to 85°C							
Humidity	Non-condensing 95%								
Mechanical Shock	MIL-STD-202, 30G half sine pulse, 11 ms								
Vibration	MIL-STD-202, 50G Hall sine pulse, 11 His MIL-STD-202, 5G swept sine, 10 to 2000 Hz								
Washing Conditions	Washing with water or alcohol based detergent allowed only with final enough drying stage								
Soldering Conditions		er only – not reflow compatible			iai criougii (arying stage			
Coldoning Containons	Triand dollars trilly indictions compatible 200 of ros(on pino)								